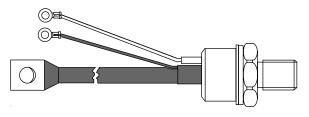


Vishay High Power Products

Phase Control Thyristors (Stud Version), 180 A



TO-209AB (TO-93)

PRODUCT SUMMARY		
I _{T(AV)}	180 A	

FEATURES

- · Hermetic glass-metal seal
- International standard case TO-209AB (TO-93)



- · RoHS compliant
- Designed and qualified for industrial level

TYPICAL APPLICATIONS

- · DC motor controls
- · Controlled DC power supplies
- AC controllers

	S AND CHARACTERISTICS	VALUES	LIMITO	
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
L		180	Α	
$I_{T(AV)}$	T _C	80	°C	
I _{T(RMS)}		285	Α	
I _{TSM}	50 Hz	3800	Α	
	60 Hz	4000		
l²t	50 Hz	72	1.42-	
1-1	60 Hz	66	kA ² s	
V _{DRM} /V _{RRM}		400 to 1000	V	
tq	Typical	100	μs	
T _J		- 40 to 125	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA				
	40	400	500					
180/181RKI	80	800	900	30				
	100	1000	1100					

180/181RKI Series

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ABSOLUTE MAXIMUM RATIN	GS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average on-state current	I	190° condu	180° conduction, half sine wave		180	Α
at case temperature	I _{T(AV)}	100 Condu	ction, nan sine v	vave	80	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 79 °C	case temperati	ure	285	Α
		t = 10 ms	No voltage		3800	
Maximum peak, one-cycle	,	t = 8.3 ms	reapplied		4000	A kA ² s
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		3500	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	3660	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage	initial T _J = T _J maximum	72	
		t = 8.3 ms	reapplied		66	
		t = 10 ms	100 % V _{RRM}		61	
		t = 8.3 ms	reapplied		56	
Maximum I ² √t for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied		reapplied	720	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π x I _{T(AV)} < I < π x I _{T(AV)}), T _J = T _J maximum		$I_{T(AV)}$, $T_J = T_J$ maximum	0.83	V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.89	V	
Low level value of on-state slope resistance	r _{t1}	$(16.7 \% \text{ x } \pi \text{ x } I_{T(AV)} < I < \pi \text{ x } I_{T(AV)}), T_J = T_J \text{ maximum}$		0.92	mΩ	
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.81	11122	
Maximum on-state voltage	V_{TM}	$I_{pk} = 570 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$		1.35	V	
Maximum holding current	I _H	T _ 05 °C	anada aunnis 1	2 V registive lead	600	mΛ
Typical latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load		1000	mA	

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%$ V_{DRM}	300	A/μs	
Typical delay time	t _d	Gate current 1 A, $dI_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}$, $T_J = 25 °C$	1.0	110	
Typical turn-off time	t _q	$I_{TM} = 50 \text{ A}, T_J = T_J \text{ maximum, dI/dt} = 10 \text{ A/}\mu\text{s},$ $V_R = 100 \text{ V, dV/dt} = 20 \text{ V/}\mu\text{s}$	100	μs	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	30	mA

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TRIGGERING							
PARAMETER	SYMBOL	TEGT COMPLETIONS		VALUES		UNITS	
PARAMETER	STINIBUL	'	EST CONDITIONS	TYP.	MAX.	UNITS	
Maximum peak gate power	P_{GM}	$T_J = T_J \text{ maximum}$	$t_p \le 5 \text{ ms}$	1	0	W	
Maximum average gate power	P _{G(AV)}	$T_J = T_J \text{ maximum}$	f = 50 Hz, d% = 50	2	.0	VV	
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	, $t_p \le 5 \text{ ms}$	3	.0	Α	
Maximum peak positive gate voltage	+V _{GM}	$T_J = T_J$ maximum, $t_p \le 5$ ms		20		0	V
Maximum peak negative gate voltage	-V _{GM}			5.0		V	
	I _{GT}	T _J = - 40 °C	Maximum required gate trigger/ current/voltage are the lowest	130	-	mA	
DC gate current required to trigger		T _J = 25 °C		65	150		
		T _J = 125 °C		35	-		
		T _J = - 40 °C	value which will trigger all units 12 V anode to cathode applied	2.0	-		
DC gate voltage required to trigger	V_{GT}	T _J = 25 °C		1.2	2.5	V	
		T _J = 125 °C		0.9	-		
DC gate current not to trigger	I _{GD}	T - T movimum	Maximum gate current/voltage not to trigger is the maximum	10		mA	
DC gate voltage not to trigger	V _{GD}	$T_J = T_J \text{ maximum}$	value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.25		V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction temperature range	TJ		- 40 to 125	°C	
Maximum storage temperature range	T _{Stg}		- 40 to 150		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.15	K/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.04	N/VV	
Mounting torque, ± 10 %		Non-lubricated threads	31 (275)	N · m	
Mounting torque, ± 10 %		Lubricated threads	24.5 (210)	(lbf · in)	
Approximate weight			280	g	
Case style		See dimensions - link at the end of datasheet TO-209AB (TO-9		O-93)	

△R _{thJC} CONDUCTION							
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS			
180°	0.050	0.032					
120°	0.063	0.059					
90°	0.080	0.082	$T_J = T_J \text{ maximum}$	K/W			
60°	0.118	0.124					
30°	0.225	0.228					

Note

 $\bullet \ \ \, \text{The table above shows the increment of thermal resistance } \, R_{thJC} \, \text{when devices operate at different conduction angles than DC} \,$

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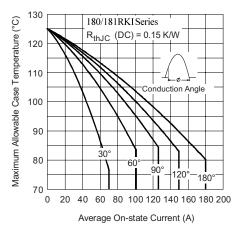


Fig. 1 - Current Ratings Characteristics

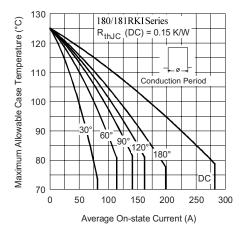


Fig. 2 - Current Ratings Characteristics

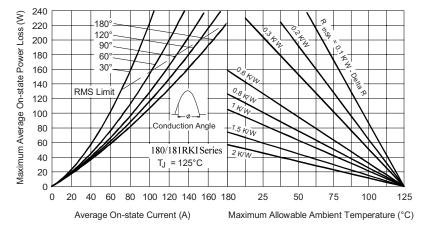


Fig. 3 - On-State Power Loss Characteristics

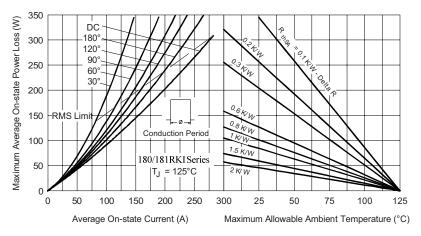


Fig. 4 - On-State Power Loss Characteristics

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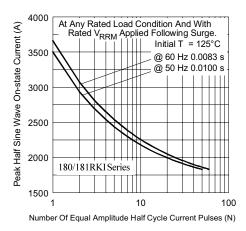


Fig. 5 - Maximum Non-Repetitive Surge Current

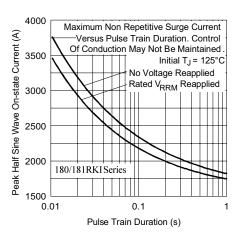


Fig. 6 - Maximum Non-Repetitive Surge Current

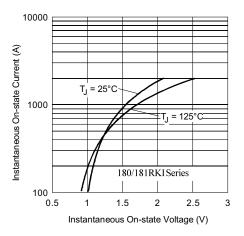


Fig. 7 - On-State Voltage Drop Characteristics

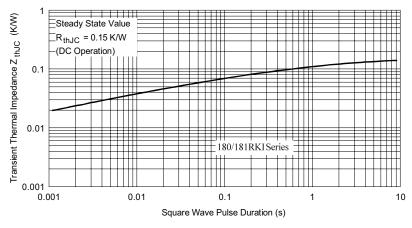


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

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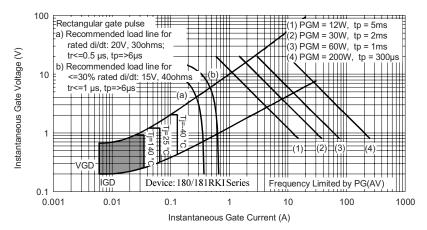
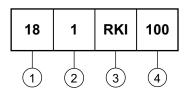


Fig. 9 - Gate Characteristics

ORDERING INFORMATION TABLE

Device code



1 - I_{T(AV)} rated average output current (rounded/10)

2 - 0 = Eyelet terminals (gate and auxiliary cathode leads)

1 = Fast-on terminals (gate and auxiliary cathode leads)

3 - Thyristor

Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

LINKS TO RELAT	TED DOCUMENTS
Dimensions	http://www.vishay.com/doc?95077

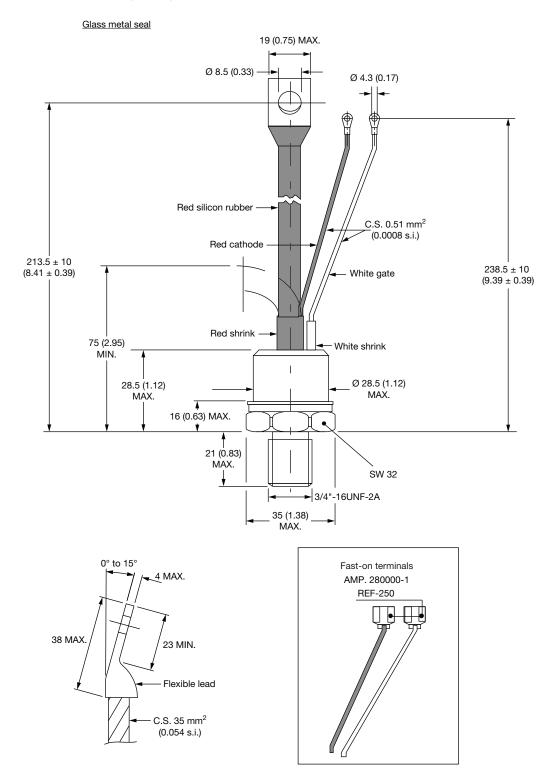
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Vishay Semiconductors

TO-209AB (TO-93)

DIMENSIONS in millimeters (inches)





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